



Vishay General Semiconductor

Surface Mount Ultrafast Rectifier



DO-214AB (SMC)

PRIMARY CHARACTERISTICS					
I _{F(AV)}	3.0 A				
V_{RRM}	100 V, 150 V, 200 V				
I _{FSM}	80 A				
t _{rr}	25 ns				
V _F at I _F = 3.0 A	0.75 V				
T _J max.	175 °C				

FEATURES

- · Low profile package
- · Ideal for automated placement
- · Oxide planar chip junction
- Ultrafast recovery times for high frequency
 RoHS
 COMPLIAN
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Solder dip 260 °C, 40 s
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

TYPICAL APPLICATIONS

For use in secondary rectification and freewheeling for ultrafast switching speeds of ac-to-ac and dc-to-dc converters in high temperature conditions for both consumer and automotive applications.

MECHANICAL DATA

Case: DO-214AB (SMC)

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC Q101 qualified), meets JESD 201 class 2

whisker test

Polarity: Color band denotes cathode end

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	UH3B	UH3C	UH3D	UNIT
Device marking code		НВ	HC	HD	
Maximum repetitive peak reverse voltage	V_{RRM}	100	150	200	V
Maximum average forward rectified current (Fig. 1)	I _{F(AV)}	2.5 ⁽¹⁾ 3.0 ⁽²⁾			А
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	80			А
Operating junction and storage temperature range	T _J , T _{STG}	- 55 to + 175			°C

Notes:

- (1) Free air, mounted on recommended copper pad area
- (2) Units mounted on P.C.B. with 0.31 x 0.31" (8.0 x 8.0 mm) copper pad area

UH3B, UH3C & UH3D

Vishay General Semiconductor



ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage ⁽¹⁾	I _F = 1.5 A I _F = 3.0 A	T _A = 25 °C	V _F	0.85 0.95	1.05	V
	I _F = 1.5 A I _F = 3.0 A	T _A = 125 °C		0.65 0.75	- 0.90	
Reverse current (2)	rated V _R	T _A = 25 °C T _A = 125 °C	I _R	- 15	- 100	μА
Maximum reverse recovery time	I _F = 0.5 A, I _R = 1.0 A, I _{rr} = 0.25 A	T - 25 °C	A = 25 °C t _{rr}	14	25	- ns
Typical reverse recovery time	$I_F = 1.0 \text{ A}, \text{ dI/dt} = 50 \text{ A/}\mu\text{s}, \ V_R = 30 \text{ V}, I_{rr} = 0.1 I_{RM}$	1 _A =25 C		23	40	
Typical softness factor (t _b /t _a)			S	1.0	-	
Typical reverse recovery current	$I_F = 3.0 \text{ A}, \text{ dI/dt} = 200 \text{ A/}\mu\text{s},$ $V_B = 200 \text{ V}$	T _A = 125 °C	I _{RM}	5.0	7.0	Α
Typical stored charge	- n = = = = = = = = = = = = = = = = = =		Q _{rr}	60	-	nC
Typical junction capacitance	4.0 V, 1 MHz		CJ	42	-	pF

Notes:

(1) Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	UH3B	UH3C	UH3D	UNIT
Typical thermal resistance (1)	$R_{ hetaJA} \ R_{ hetaJM}$	95 12		°C/W	

Note:

(1) Free air, mounted on recommended copper pad area. Thermal resistance $R_{\theta JA}$ - junction to ambient, $R_{\theta JM}$ - junction to mount

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
UH3D-E3/57T	0.236	57T	850	7" diameter plastic tape and reel		
UH3D-E3/9AT	0.236	9AT	3500	13" diameter plastic tape and reel		
UH3DHE3/57T (1)	0.236	57T	850	7" diameter plastic tape and reel		
UH3DHE3/9AT (1)	0.236	9AT	3500	13" diameter plastic tape and reel		

Note:

(1) Automotive grade AEC Q101 qualified



Vishay General Semiconductor

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

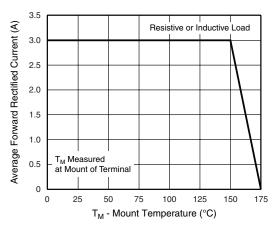


Figure 1. Maximum Forward Current Derating Curve

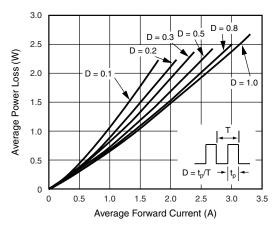


Figure 2. Forward Power Loss Characteristics

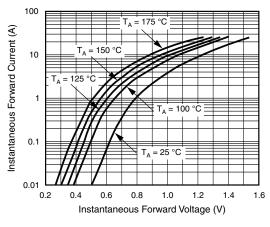


Figure 3. Typical Instantaneous Forward Characteristics

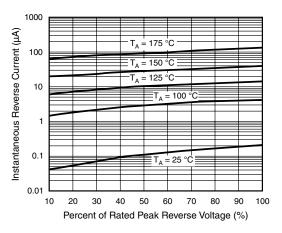


Figure 4. Typical Reverse Characteristics

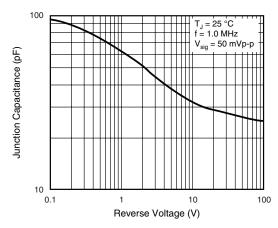


Figure 5. Typical Junction Capacitance

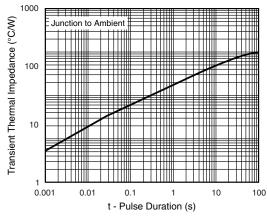


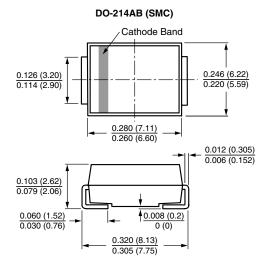
Figure 6. Typical Transient Thermal Impedance

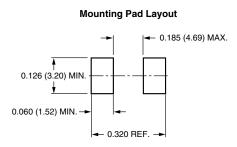
UH3B, UH3C & UH3D

Vishay General Semiconductor



PACKAGE OUTLINE DIMENSIONS in inches (millimeters)







Vishay

Disclaimer

All product specifications and data are subject to change without notice.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained herein or in any other disclosure relating to any product.

Vishay disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications unless otherwise expressly indicated. Customers using or selling Vishay products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Vishay for any damages arising or resulting from such use or sale. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

Product names and markings noted herein may be trademarks of their respective owners.

Revision: 18-Jul-08

Document Number: 91000 www.vishay.com